N-Channel 30-V (D-S) MOSFET

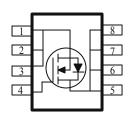
These miniature surface mount MOSFETs utilize High Cell Density process. Low r_{DS(on)} assures minimal power loss and conserves energy, making this device ideal for use in power management circuitry. Typical applications are PWMDC-DC converters, power management in portable and battery-powered products such as computers, printers, battery charger, telecommunication power system, and telephones power system.

•	Low r _{DS(on)} Provides Higher Efficiency and
	Extends Battery Life

- Miniature SO-8 Surface Mount Package Saves Board Space
- High power and current handling capability
- Low side high current DC-DC Converter applications

PRODUCT SUMMARY				
$V_{DS}(V)$	$r_{DS(on)} m(\Omega)$	$I_{D}(A)$		
30	$22 @ V_{GS} = 10V$	9.0		
30	$36 @ V_{GS} = 4.5V$	7.0		





ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C UNLESS OTHERWISE NOTED)						
Parameter			Limit	Units		
Drain-Source Voltage			30	V		
Gate-Source Voltage			±20	·		
Continuous Drain Current ^a	T _A =25°C		9.0			
Continuous Drain Current	$T_A = 25^{\circ} \text{C}$ $T_A = 70^{\circ} \text{C}$	T _D	7.4	A		
Pulsed Drain Current ^b	I_{DM}	30				
Continuous Source Current (Diode Conduction) ^a		I_S	1.6	A		
Decree Discipation ⁸	$T_A=25^{\circ}C$	D	3.1	W		
Power Dissipation ^a	$T_A=25^{\circ}C$ $T_A=70^{\circ}C$		2.0	• • •		
Operating Junction and Storage Temperature Range		T_J, T_{stg}	-55 to 150	°C		

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Maximum	Units		
N	t <= 10 sec	D	40	°C/W		
Maximum Junction-to-Ambient ^a	Steady-State	$R_{ heta JA}$	70	°C/W		

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Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

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Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Static						
Gate-Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_{D} = 250 \text{ uA}$	1			V
Gate-Body Leakage	I_{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = 20 \text{ V}$			±100	nA
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}$ $V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}, T_J = 55^{\circ}\text{C}$			1 25	uA
On-State Drain Current ^A	I _{D(on)}	$V_{DS} = 5 \text{ V}, V_{GS} = 10 \text{ V}$	20			A
Drain-Source On-Resistance ^A	r _{DS(on)}	$V_{GS} = 10 \text{ V}, I_D = 9 \text{ A}$ $V_{GS} = 4.5 \text{ V}, I_D = 7 \text{ A}$			22 36	mΩ
Forward Tranconductance ^A	g_{fs}	$V_{DS} = 15 \text{ V}, I_{D} = 9 \text{ A}$		40		S
Diode Forward Voltage	V_{SD}	$I_S = 2.3 \text{ A}, V_{GS} = 0 \text{ V}$		0.7		V
Dynamic ^b						
Total Gate Charge	Q_{g}	$V_{DS} = 15 \text{ V}, V_{GS} = 4.5 \text{ V},$ $I_{D} = 9 \text{ A}$		4.0		
Gate-Source Charge	Q_{gs}			1.1		nC
Gate-Drain Charge	Q_{gd}			1.4		1
Turn-On Delay Time	$t_{d(on)}$			16		
Rise Time	$t_{\rm r}$	$V_{DD} = 25 \text{ V}, R_L = 25 \Omega, I_D = 1 \text{ A},$		5		
Turn-Off Delay Time	$t_{d(off)}$	$V_{GEN} = 10 \text{ V}$		23		nS
Fall-Time	t_{f}			3		
Source-Ddrain Reverse Recovery Ti	t_{rr}	$I_F = 2.3 \text{ A, Di/Dt} = 100 \text{ A/uS}$		41		

Notes

- a. Pulse test: PW <= 300us duty cycle <= 2%.
- b. Guaranteed by design, not subject to production testing.

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Typical Electrical Characteristics (N-Channel)

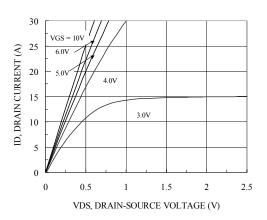


Figure 1. On-Region Characteristics

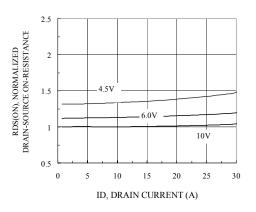


Figure 3. On Resistance Vs Vgs Voltage

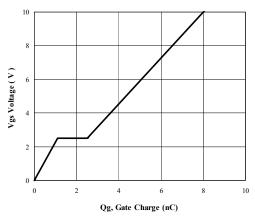


Figure 5. Gate Charge Characteristics

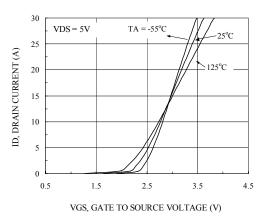


Figure 2. Body Diode Forward Voltage Variation with Source Current and Temperature

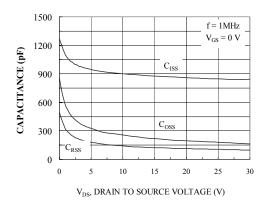


Figure 4. Capacitance Characteristics

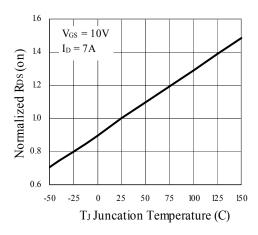
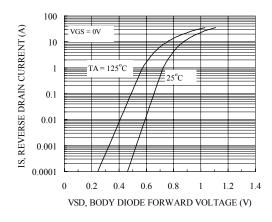


Figure 6. On-Resistance Variation with Temperature

AO4414/MC4414

Typical Electrical Characteristics (N-Channel)



Freescale

Figure 7. Transfer Characteristics

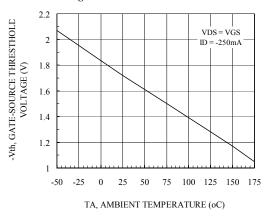


Figure 9. Vth Gate to Source Voltage Vs Temperature

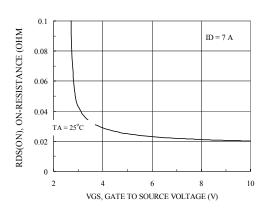


Figure 8. On-Resistance with Gate to Source Voltage

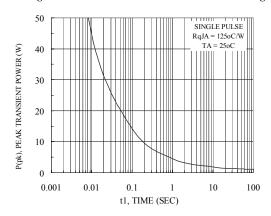


Figure 10. Single Pulse Maximum Power Dissipation

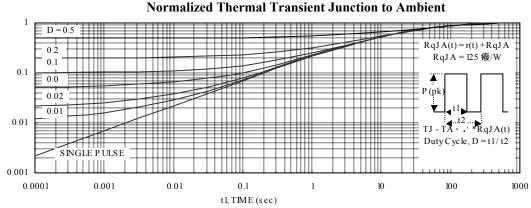
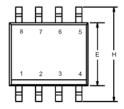
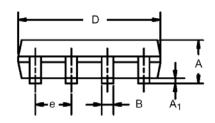


Figure 11. Transient Thermal Response Curve

Package Information

SO-8: 8LEAD





	MILLIN	IETERS	INC	HES
Dim	Min	Max	Min	Max
Α	1.35	1.75	0.053	0.069
A ₁	0.10	0.20	0.004	0.008
В	0.35	0.51	0.014	0.020
С	0.19	0.25	0.0075	0.010
D	4.80	5.00	0.189	0.196
E	3.80	4.00	0.150	0.157
е	1.27	BSC	0.050	BSC
Н	5.80	6.20	0.228	0.244
h	0.25	0.50	0.010	0.020
L	0.50	0.93	0.020	0.037
q	0°	8°	0°	8°

